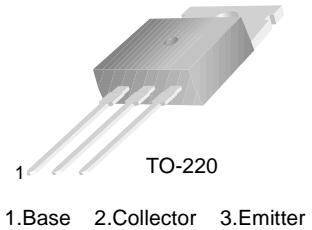


### High Voltage Switching

- Use In Horizontal Deflection Output Stage



### NPN Epitaxial Silicon Transistor

**Absolute Maximum Ratings**  $T_C=25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	330	V
$V_{CEO}$	Collector-Emitter Voltage	150	V
$V_{EBO}$	Emitter-Base Voltage	6	V
$I_C$	Collector Current (DC)	7	A
$I_{CP}$	Collector Current (Pulse)	10	A
$I_B$	Base Current	4	A
$P_C$	Collector Dissipation ( $T_C=25^\circ\text{C}$ )	60	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature	- 65 ~ 150	$^\circ\text{C}$

**Electrical Characteristics**  $T_C=25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
$I_{CES}$	Collector Cut-off Current	$V_{CE} = 330\text{V}$ , $V_{BE} = 0$ $V_{CE} = 200\text{V}$ , $V_{BE} = 0$ $V_{CE} = 200\text{V}$ , $V_{BE} = 0$ @ $T_C = 150^\circ\text{C}$		5 100 1	$\mu\text{A}$ $\text{mA}$
$I_{EBO}$	Emitter Cut-off Current	$V_{BE} = 6\text{V}$ , $I_C = 0$		1	$\text{mA}$
$V_{CE(\text{sat})}$	Collector-Emitter Saturation Voltage : BU407 : BU407H	$I_C = 5\text{A}$ , $I_B = 0.5\text{A}$ $I_C = 5\text{A}$ , $I_B = 0.8\text{A}$		1 1	V
$V_{BE(\text{sat})}$	Base-Emitter Saturation Voltage : BU407 : BU407H	$I_C = 5\text{A}$ , $I_B = 0.5\text{A}$ $I_C = 5\text{A}$ , $I_B = 0.8\text{A}$		1.2 1.2	V
$f_T$	Current Gain Bandwidth Product	$V_{CE} = 10\text{V}$ , $I_C = 0.5\text{A}$	10		MHz
$t_{OFF}$	Turn OFF Time : BU407 : BU407H	$I_C = 5\text{A}$ , $I_B = 0.5\text{A}$ $I_C = 5\text{A}$ , $I_B = 0.8\text{A}$		0.75 0.4	$\mu\text{s}$

## Typical Characteristics

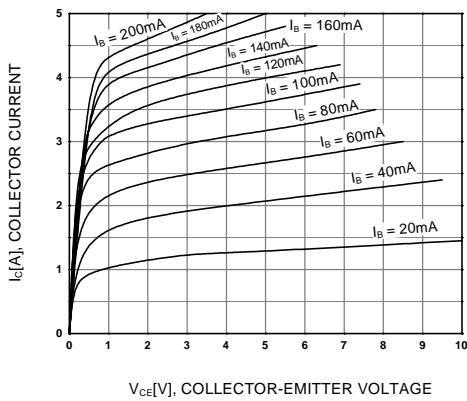


Figure 1. Static Characteristic

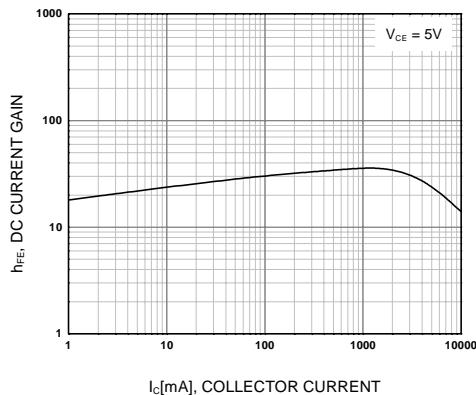


Figure 2. DC current Gain

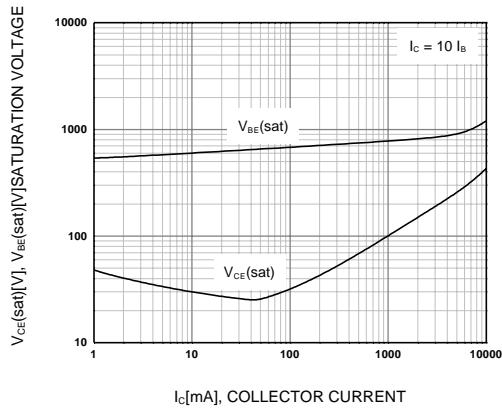


Figure 3. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

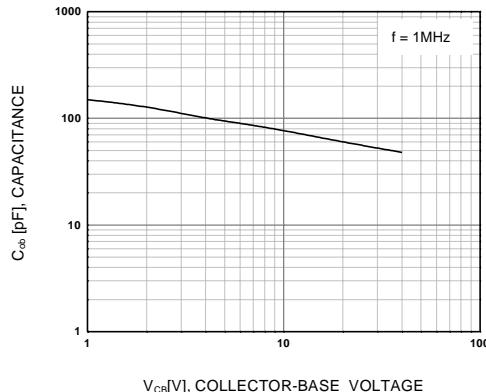


Figure 4. Collector Output Capacitance

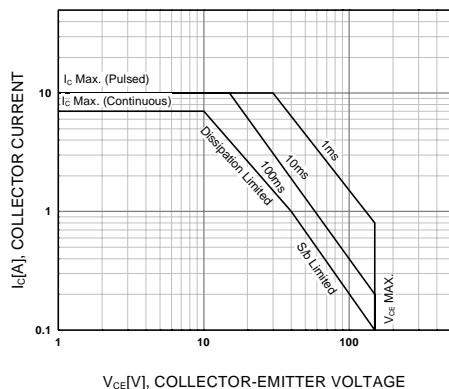


Figure 5. Safe Operating Area

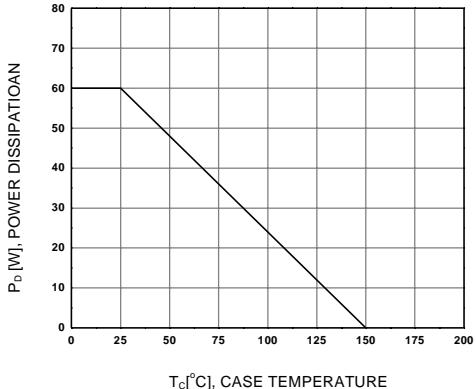
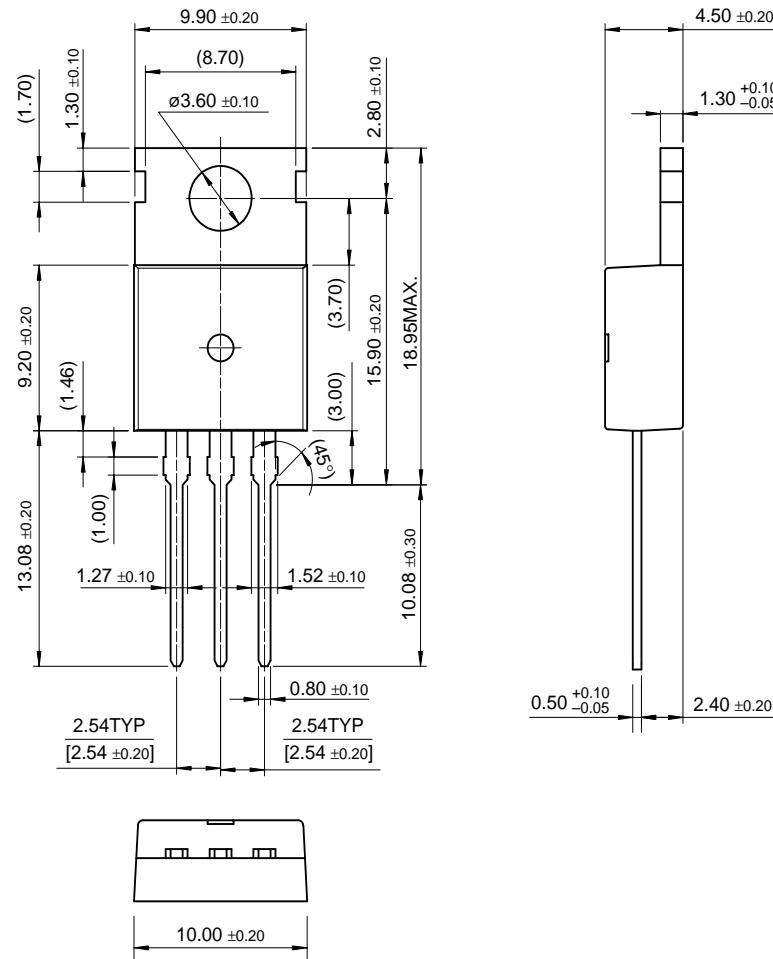


Figure 6. Power Derating

## Package Demensions

## TO-220



Dimensions in Millimeters

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